

Highly efficient intrinsic phosphorescence from a σ-conjugated poly(silylene) polymer

S. Toliautas, J. Sulskus, A. Kadashchuk, Yu. Skryshevski, A. Vakhnin, <u>R. Augulis</u>, V. Gulbinas, S. Nespurek, J. Genoe, L. Valkunas



Overview



Experiments

The data presented in figure **below** prove unambiguously the existence of two different spectral components in delayed emission spectra of PBMSi, namely the broad structureless band and the red-shifted well-structured narrow spectral component with the main peak at 460 nm. These spectral components feature very different decay times and are identified as delayed fluorescence and intrinsic phosphorescence of PBMSi.



We have observed highly efficient intrinsic phosphorescence of a neat σ-conjugated polymer, poly[biphenyl(methyl)silylene] (PBMSi). At low temperatures, PBMSi solid films feature ~15% phosphorescence quantum yield, which is unusually high for purely organic conjugated polymers and is comparable to that of organometallic compounds.

Calculations



In contrast to the other conjugated polymers, the observed phosphorescence in PBMSi is so strong that it can be readily observable even in cw-PL spectra of the solid films (below) for which Ph quenching is expected to be severe because of triplet migration.

The properties of the oligomer model of the compound (above) were computed using *Gaussian09* package. DFT theory with B3LYP functional and 6-31G(d,p) basis set was used. The proposed energy conversion path is shown in an energy diagram below. The TD-DFT calculations yield the triplet state of the CT character, T_3^{CT} , to be located just below the S^{CT} , implying a very small singlet-triplet splitting for the intramolecular charge transfer excitations in this material. The proximity of CT states is very favorable for enhanced intersystem crossing rate.



